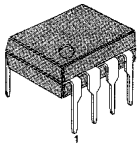
KA741/E/I SINGLE OPERATIONAL AMPLIFIER

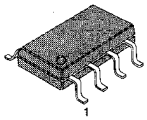
SINGLE OPERATIONAL AMPLIFIERS

The KA741 series are general purpose operational amplifiers which feature improved performance over industry standards like the KA709. It is intended for a wide range of analog applications.
The high gain and wide range of operating voltage provide superior performance in intergrator, summing amplifier, and general feedback applications.

8 DIP



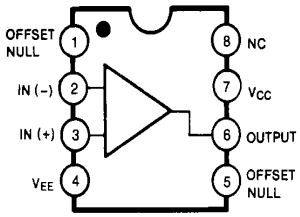
8 SOP



FEATURES

- Short circuit protection
- Excellent temperature stability
- Internal frequency compensation
- High Input voltage range
- Null of offset

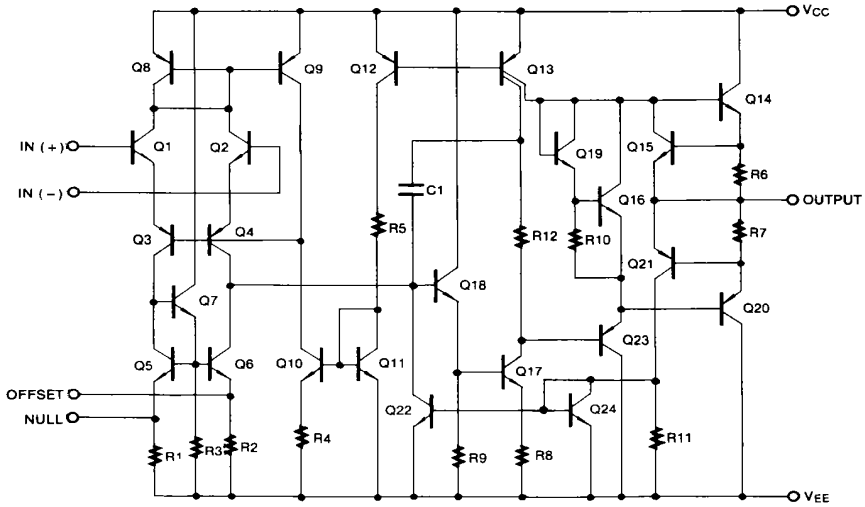
BLOCK DIAGRAM



ORDERING INFORMATION

Device	Package	Operating Temperature
KA741E KA741	8 DIP	0 ~ + 70℃
KA741ED KA741D	8 SOP	
KA741I KA741EI	8 DIP	-40 ~ +85℃
KA7411ID KA741EID	8 SOP	

SCHEMATIC DIAGRAM



ELECTRONICS

ABSOLUTE MAXIMUM RATINGS (T_A=25℃)

Characteristic	Symbol	KA741	KA741E	KA741I	Unit
Supply Voltage	V_{CC}	± 18	± 22	± 18	V
Differential Input Voltage	$V_{I(DIFF)}$	± 30	± 30	± 30	V
Input Voltage	V_I	± 15	± 15	± 15	V
Output Short Circuit Duration		Indefinite	Indefinite	Indefinite	
Power Dissipation	P_D	500	500	500	mW
Operating Temperature Range	T_{OPR}	0 ~ + 70	0 ~ + 70	-40 ~ + 85	℃
Storage Temperature Range	T_{STG}	-65 ~ + 150	-65 ~ + 150	-65 ~ + 150	℃

ELECTRICAL CHARACTERISTICS

(V_{CC} = 15V, V_{EE} = - 15V. T_A = 25℃, unless otherwise specified)

Characteristic	Symbol	Test Conditions		KA741E			KA741/KA741I			Unit
				Min	Typ	Max	MIn	Typ	Max	
Input Offset Voltage	V_{IO}	R_S≤ 10KΩ						2.0	6.0	mV
		R_S≤ 50Ω			0.8	3.0				
Input Offset Voltage Adjustment Range	$V_{IO(R)}$	V_{CC} = ± 20V		± 10				± 15		mV
Input Offset Current	I_{IO}				3.0	30		20	200	nA
Input Bias Current	I_{BIAS}				30	80		80	500	nA
Input Resistance	R_I	V_{CC} =± 20V		1.0	6.0		0.3	2.0		MΩ
Input Voltage Range	$V_{I(R)}$			± 12	± 13		± 12	± 13		V
Large Signal Voltage Gain	G_V	R_L≥ 2KΩ	V_{CC} =± 20V, $V_{O(P.P)}$ =± 15V	50						V/mV
			V_{CC} =± 15V, $V_{O(P.P)}$ =± 10V				20	200		
Output Short Circuit Current	I_{SC}			10	25	35		25		mA
Output Voltage Swing	$V_{O(P.P)}$	V_{CC} =± 20V	R_L≥ 10KΩ	± 16						V
			R_L≥ 10KΩ	± 15						
		V_{CC} =± 15V	R_L≥ 10KΩ				± 12	± 14		
			R_L≥ 10KΩ				± 10	± 13		
Common Mode Reiection Ratio	CMRR	R_S≤ 10KΩ , V_{CM} = ± 12V					70	90		dB
		R_S≤ 50KΩ , V_{CM} = ± 12V		80	95					
Power Supply Rejection Ratio	PSRR	V_{CC} =± 15V to V_{CC} =± 15V R_S≤ 50Ω		86	96					dB
		V_{CC} =± 15V to V_{CC} =± 15V R_S≤ 10KΩ					77	96		

ELECTRICAL CHARACTERISTICS (Continued)

Characteristic		Symbol	Test Conditions	KA741E			KA741/KA741I			Unit
				Min	Typ	Max	Min	Typ	Max	
Transient Response	Rise Time	t_R	Unity Gain		0.25	0.8		0.3		μs
	Overshoot	OS			6.0	20		10		%
Bandwidth		BW		0.43	1.5					MHz
Slew Rate		SR	Unity Gain	0.3	0.7			0.5		V/μs
Supply Current		I_{CC}	R_L= ∞ Ω					1.5	2.8	mA
Power Consumption		P_C	V_{CC} = ± 20V		80	150				mW
			V_{CC} = ± 15V					50	85	

ELECTRICAL CHARACTERISTICS

(-40℃≤ T_A≤ 85℃ for the KA7411, 0≤ T_A≤ 70℃ for the KA741 and KA741E. V_{CC} = ± 15V, unless otherwise specified)

Characteristic	Symbol	Test Conditions		KA741E			KA741/KA741I			Unit
				Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage	V_{IO}	R_S≤ 50Ω				4.0				mV
		R_S≤ 10KΩ							7.5	
Input Offset Voltage Drift	Δ V_{IO}/Δ T				15					μV/℃
Input Offset Current	I_{IO}					70			300	nA
Input Offset Current Drift	Δ I_{IO}/Δ T					0.5				nA/℃
Input Bias Current	I_{BIAS}					0.21			0.8	μA
Input Resistance	R_I	V_{CC} = ± 20V		0.5						MΩ
Input Voltage Range	$V_{I(R)}$			± 12	± 13		± 12	± 13		V
Output Voltage Swing	$V_{O(P.P)}$	V_{CC} =± 20V	R_S≥ 10KΩ	± 16						V
			R_S≥ 2KΩ	± 15						
		V_{CC} =± 15V	R_S≥ 10KΩ				± 12	± 14		
			R_S≥ 2KΩ				± 10	± 13		
Output Short Circuit Current	I_{SC}			10		40	10		40	mA
Common Mode Rejection Ratio	CMRR	R_S≤ 10KΩ , V_{CM} =± 12V					70	90		dB
		R_S≤ 50KΩ , V_{CM} =± 12V		80	95					
Power Supply Rejection Ratio	PSRR	V_{CC} =± 20V to ± 5V	R_S≤ 50Ω	86	96					dB
			R_S≤ 10KΩ				77	96		
Large Signal Voltage Gain	G_V	R_S≥ 2KΩ	V_{CC} =± 20V, $V_{O(P-P)}$ =± 15V	32						V/mV
			V_{CC} =± 15V, $V_{O(P.P)}$ =± 10V				15			
			V_{CC} =± 15V, $V_{O(P-P)}$ =± 2V	10						

TYPICAL PERFORMANCE CHARACTERISTICS

Fig. 7 OUTPUT RESISTANCE vs FREQUENCY

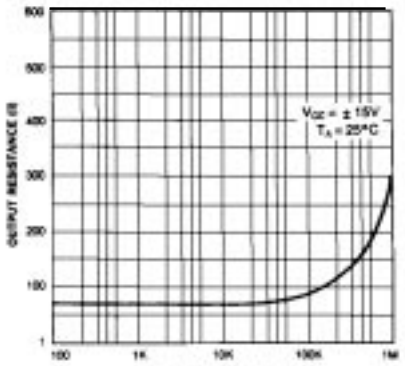


Fig. 8 INPUT RESISTANCE AND INPUT CAPACITANCE vs FREQUENCY

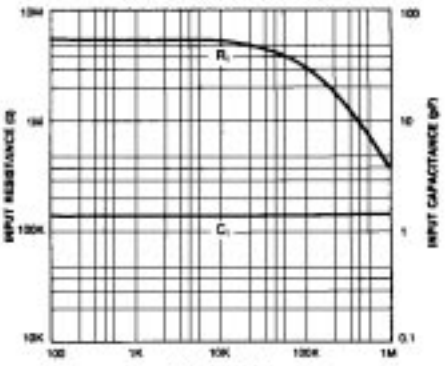


Fig. 9 INPUT BIAS CURRENT vs AMBIENT TEMPERATURE

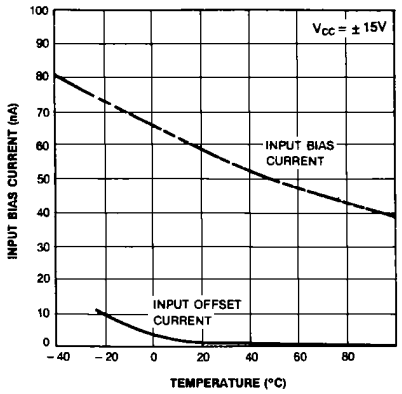


Fig. 10 POWER CONSUMPTION vs AMBIENT TEMPERATURE

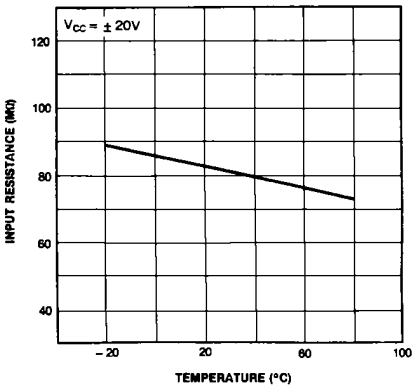


Fig. 11 INPUT OFFSET CURRENT vs AMBIENT TEMPERATURE

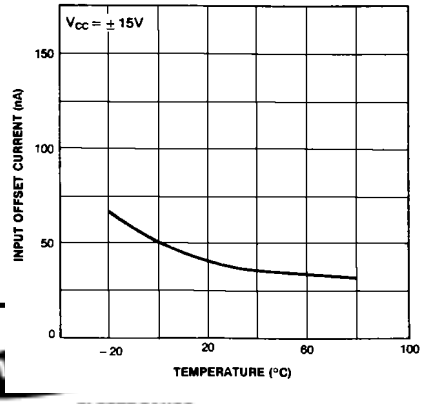


Fig. 12 INPUT RESISTANCE vs AMBIENT TEMPERATURE

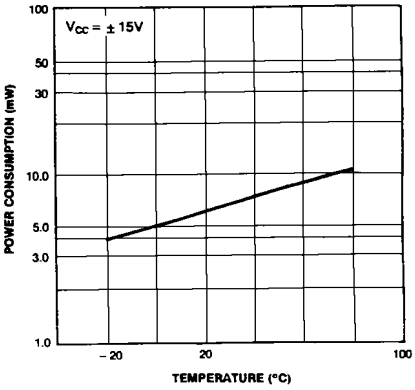


Fig. 13 NORMALIZED DC PARAMETERS vs AMBIENT TEMPERATURE

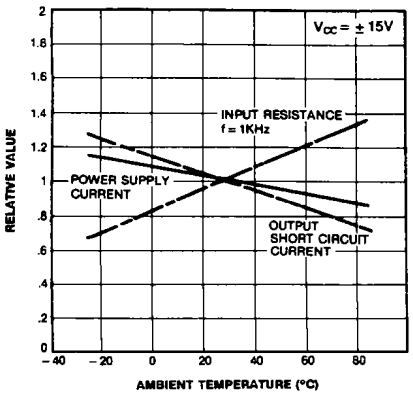


Fig. 14 FREQUENCY CHARACTERISTICS vs AMBIENT TEMPERATURE

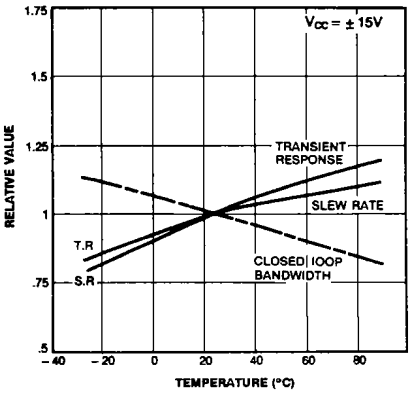


Fig. 15 FREQUENCY CHARACTERISTICS vs SUPPLY VOLTAGE

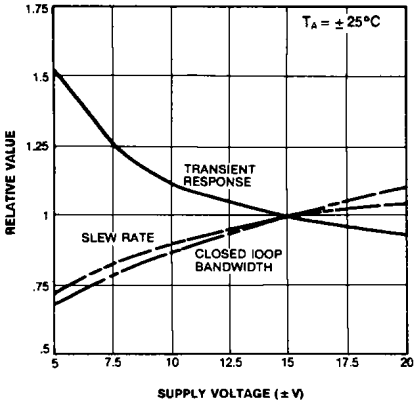


Fig. 16 OUTPUT SHORT CIRCUIT CURRENT vs AMBIENT TEMPERATURE

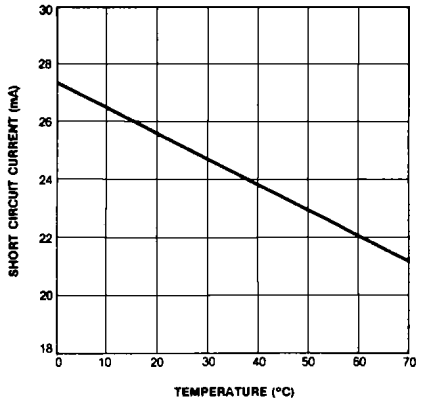


Fig. 17 TRANSIENT RESPONSE

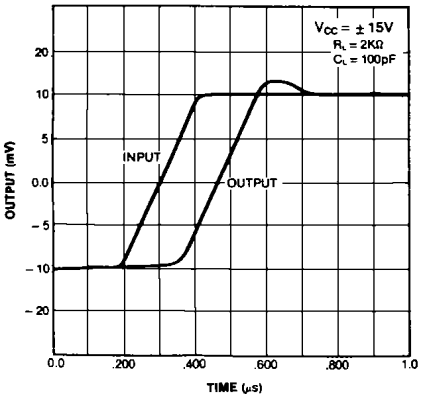


Fig. 18 COMMON-MODE REJECTION RATIO vs FREQUENCY

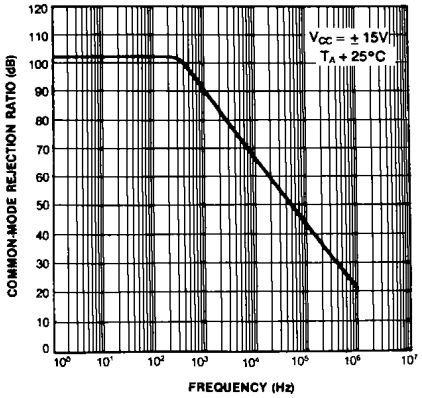


Fig. 18 VOLTAGE FOLLOWER LARGE SIGNAL PULSE RESPONSE

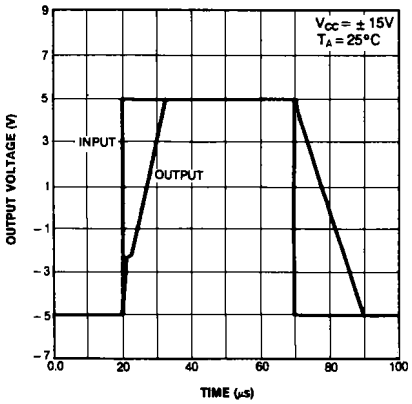
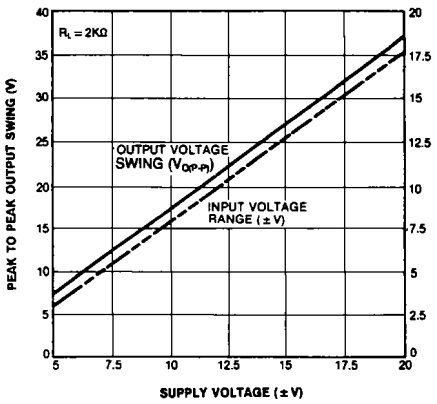
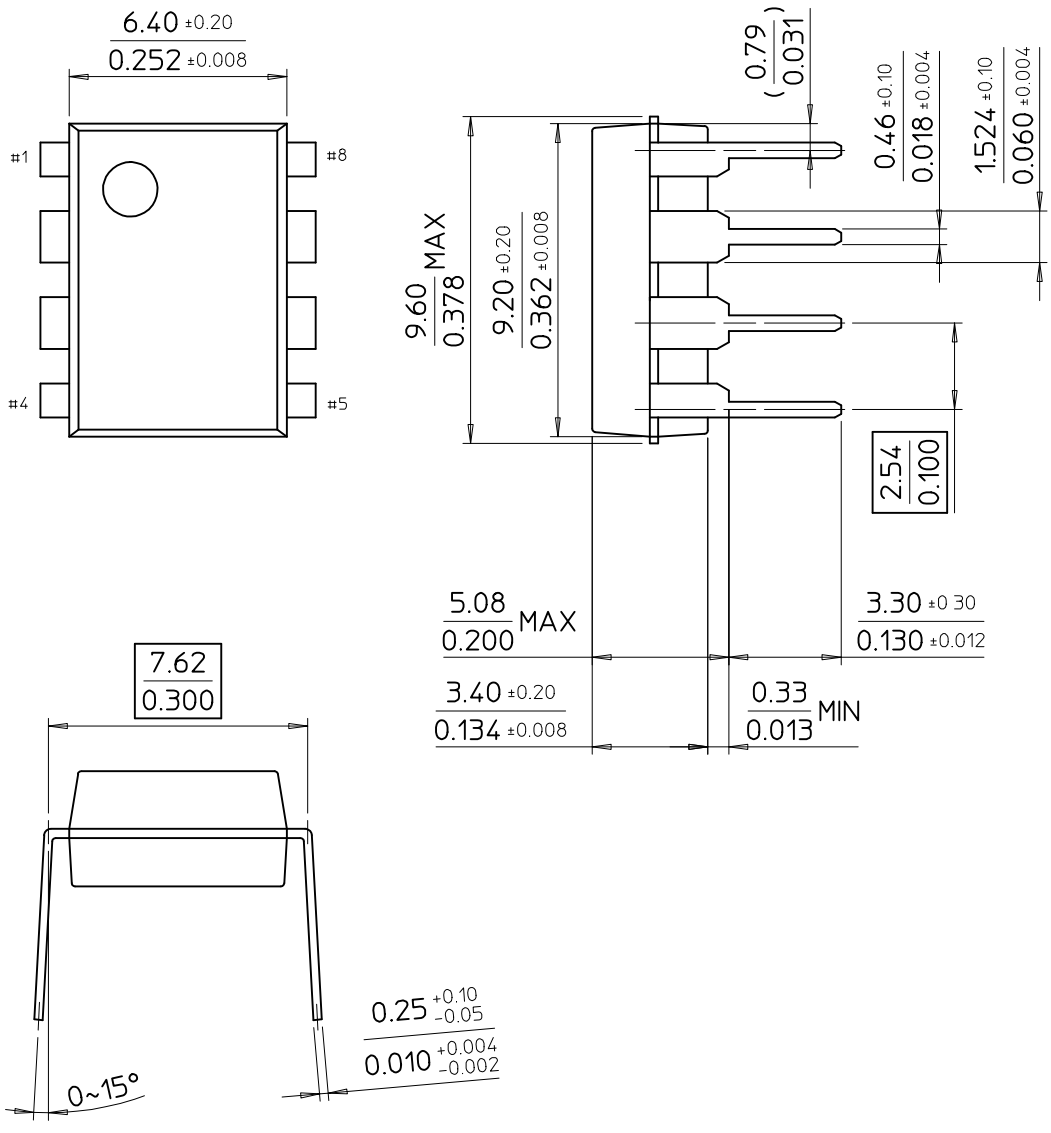


Fig. 19 OUTPUT SWING AND INPUT RANGE vs SUPPLY VOLTAGE



8–DIP–300

Dimensions in Milimeters/inches



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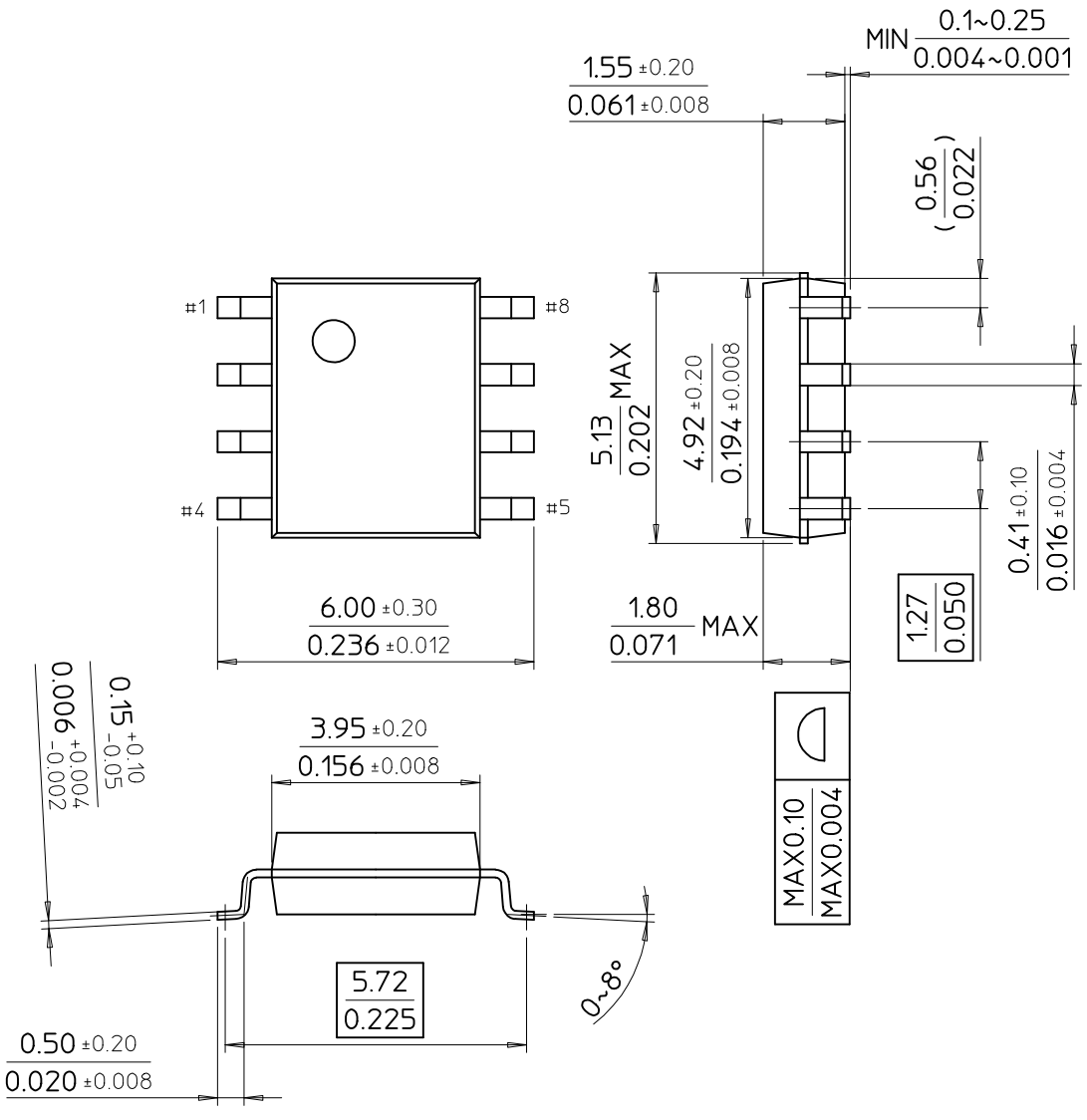
8–SOP–225

Dimensions in Milimeters/inches



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